BLF6G13L-250P; BLF6G13LS-250P(G)

Power LDMOS transistor

AMPLEON

Rev. 5. — 1 September 2015

Product data sheet

1. Product profile

1.1 General description

250 W LDMOS power transistor intended for CW applications at a frequency of 1.3 GHz.

Table 1. Test information

Typical RF performance at $T_{case} = 25$ °C; $I_{Dq} = 100$ mA; in a class-AB production test circuit.

Test signal	f	V _{DS}	P _{L(1dB)}	G _p	η_{D}
	(GHz)	(V)	(W)	(dB)	(%)
CW	1.3	50	250	17	56

1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

Industrial, scientific and medical applications

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLF6G13L-	250P (SOT1121A)		
1	drain1		
2	drain2	1 2 [^] [^]	1
3	gate1		
4	gate2		5
5	source [1]		2 sym117
BLF6G13LS	G-250P (SOT1121B)		,
1	drain1	PG PG	
2	drain2	1 2	
3	gate1		
4	gate2	3 4 5	5
5	source [1]		2 sym117
BLF6G13LS	6-250PG (SOT1121E)		
1	drain1	4 0	
2	drain2	1 2	1
3	gate1		2_
4	gate2	3 4 5	5
5	source [1]		2 sym117

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	Package					
	Name	Description	Version				
BLF6G13L-250P	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT1121A				
BLF6G13LS-250P	-	earless flanged LDMOST ceramic package; 4 leads	SOT1121B				
BLF6G13LS-250PG	-	earless flanged LDMOST ceramic package; 4 leads	SOT1121E				

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V_{DS}	drain-source voltage	-	100	V
V_{GS}	gate-source voltage	-0.5	+13	V
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature [1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T_{case} = 85 °C; P_{L} = 250 W	0.26	K/W

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.4 \text{ mA}$	100	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_{D} = 235 \text{ mA}$	1.4	1.8	2.4	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	21	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	240	nA
g _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 120 mA	-	1	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 4.75 \text{ A}$	-	200	-	mΩ

Table 7. RF characteristics

Test signal: CW; f = 1.3 GHz; RF performance at $V_{DS} = 50$ V; $I_{Dq} = 100$ mA; $T_{case} = 25$ °C; unless otherwise specified, in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DS}	drain-source voltage	P _L = 250 W	-	-	50	٧
Gp	power gain	P _L = 250 W	15	17	-	dB
RLin	input return loss	P _L = 250 W	-	-30	-20	dB
η_{D}	drain efficiency	P _L = 250 W	52	56	-	%

7. Application information

7.1 Ruggedness in class-AB operation

The BLF6G13L-250P, BLF6G13LS-250P and BLF6G13LS-250PG are capable of withstanding a load mismatch corresponding to VSWR = 5:1 through all phases under the following conditions: $V_{DS} = 50 \text{ V}$; $I_{Dq} = 100 \text{ mA}$; $P_{L} = 250 \text{ W}$; f = 1.3 GHz.

7.2 Impedance information

Table 8. Typical impedance

Typical values valid per section unless otherwise specified.

f	Z _S	Z _L optimized for G _p	Z_L optimized for η_D
(MHz)	(Ω)	(Ω)	(Ω)
1200	3.03 – j8.15	2.03 – j0.25	1.46 – j0.47
1300	4.06 – j9.52	1.67 – j0.92	1.19 – j0.95
1400	7.00 – j9.61	1.50 – j1.48	1.22 – j1.49

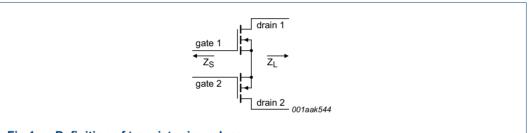


Fig 1. Definition of transistor impedance

7.3 Circuit information

Table 9. List of components

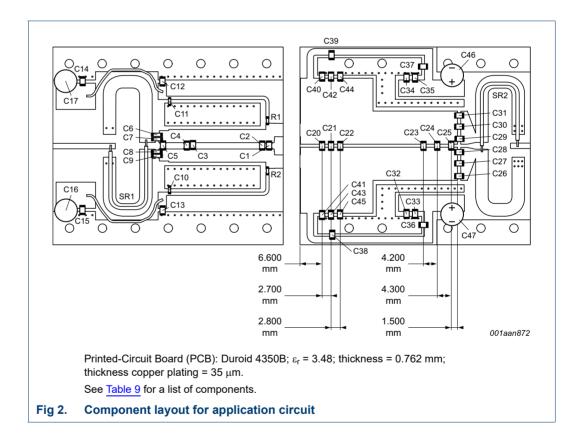
For application circuit see Figure 2.

Component	Description	Value	Remarks
C1, C2	multilayer ceramic chip capacitor	1.9 pF [1	
C3, C4	multilayer ceramic chip capacitor	4.7 pF [1	
C5	multilayer ceramic chip capacitor	10 pF [1	
C6, C7, C8, C9, C10, C11, C38, C39	multilayer ceramic chip capacitor	56 pF [1	
C12, C13	multilayer ceramic chip capacitor	100 pF [2	
C14, C15, C32, C34	multilayer ceramic chip capacitor	1 nF [2	
C16, C17	electrolytic capacitor	10 μF, 50 V	220 X5R
C20, C21, C22, C23	multilayer ceramic chip capacitor	3.0 pF [1	
C40, C41	multilayer ceramic chip capacitor	2.4 pF [1	
C42, C43, C44, C45	multilayer ceramic chip capacitor	2.7 pF [1	
C24	multilayer ceramic chip capacitor	0.8 pF [1	
C25	multilayer ceramic chip capacitor	0.6 pF [1	

Table 9. List of components ...continued For application circuit see Figure 2.

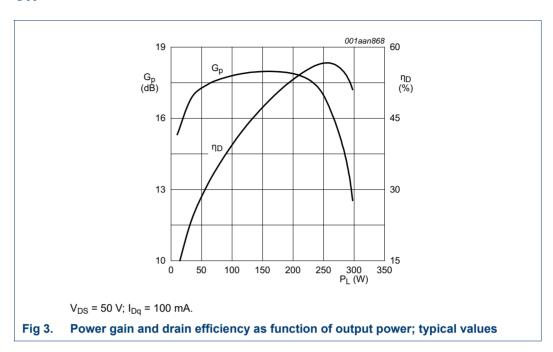
Component	Description	Value	Remarks
C26, C27, c28, C29, C30, C31, C33, C35	multilayer ceramic chip capacitor	100 pF [1]	
C36, C37	multilayer ceramic chip capacitor	20 nF [3]	
C46, C47	electrolytic capacitor	100 μF, 63 V	
R1, R2	SMD resistor 0603	5.1 Ω	
SR1	COAX	25 Ω	UT-141C-25-TP
SR2	COAX	35 Ω	UT-141C-35-TP

- [1] American Technical Ceramics type 800B or capacitor of same quality.
- [2] American Technical Ceramics type 100B or capacitor of same quality.
- [3] American Technical Ceramics type 200B or capacitor of same quality.

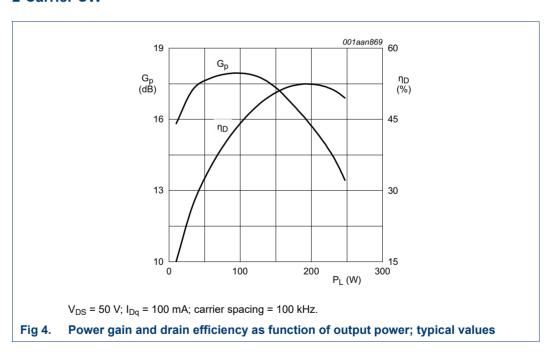


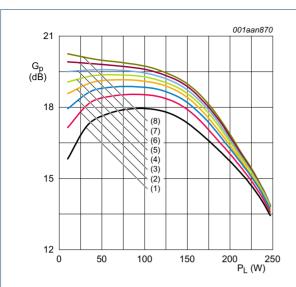
7.4 Graphical data

7.4.1 CW



7.4.2 2-Carrier CW

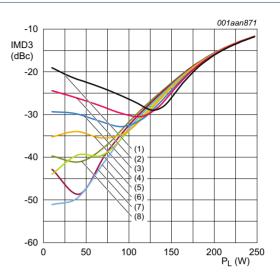




 V_{DS} = 50 V; f = 1300 MHz; carrier spacing = 100 kHz.

- (1) $I_{Dq} = 100 \text{ mA}$
- (2) $I_{Dq} = 300 \text{ mA}$
- (3) $I_{Dq} = 500 \text{ mA}$
- (4) $I_{Dq} = 700 \text{ mA}$
- (5) $I_{Dq} = 900 \text{ mA}$
- (6) $I_{Dq} = 1100 \text{ mA}$
- (7) $I_{Dq} = 1300 \text{ mA}$
- (8) $I_{Dq} = 1500 \text{ mA}$

Fig 5. Power gain as a function of output power; typical values



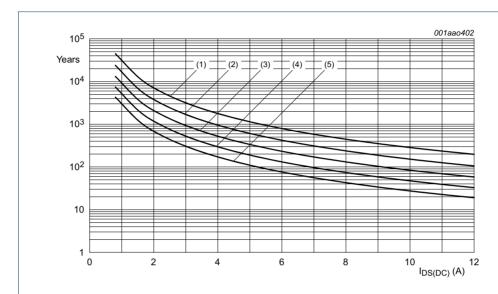
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- (1) $I_{Dq} = 100 \text{ mA}$
- (2) $I_{Dq} = 300 \text{ mA}$
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- (5) $I_{Dq} = 900 \text{ mA}$
- (6) $I_{Dq} = 1100 \text{ mA}$
- (7) $I_{Dq} = 1300 \text{ mA}$
- (8) $I_{Dq} = 1500 \text{ mA}$

Fig 6. Third order intermodulation distortion as a function of output power; typical values

8. Test information

8.1 Reliability



MTTF (Years)

The reliability at pulsed conditions can be calculated as follows: MTTF x 1 / δ .

- (1) $T_i = 130 \, ^{\circ}C$
- (2) $T_j = 140 \, ^{\circ}C$
- (3) $T_i = 150 \, ^{\circ}\text{C}$
- (4) $T_j = 160 \, ^{\circ}C$
- (5) $T_j = 170 \, ^{\circ}\text{C}$

Fig 7. Electromigration (I_{DS(DC)}, total device)

9. Package outline

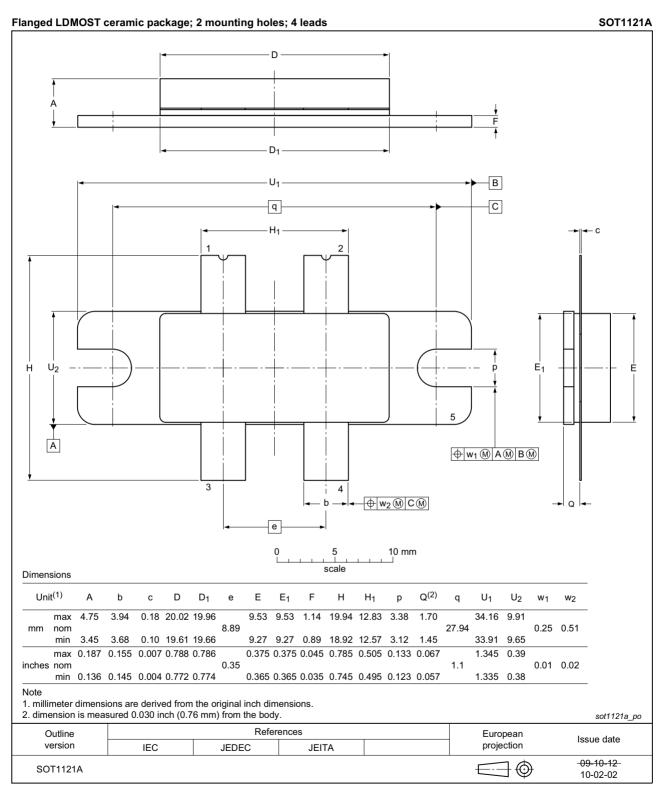


Fig 8. Package outline SOT1121A

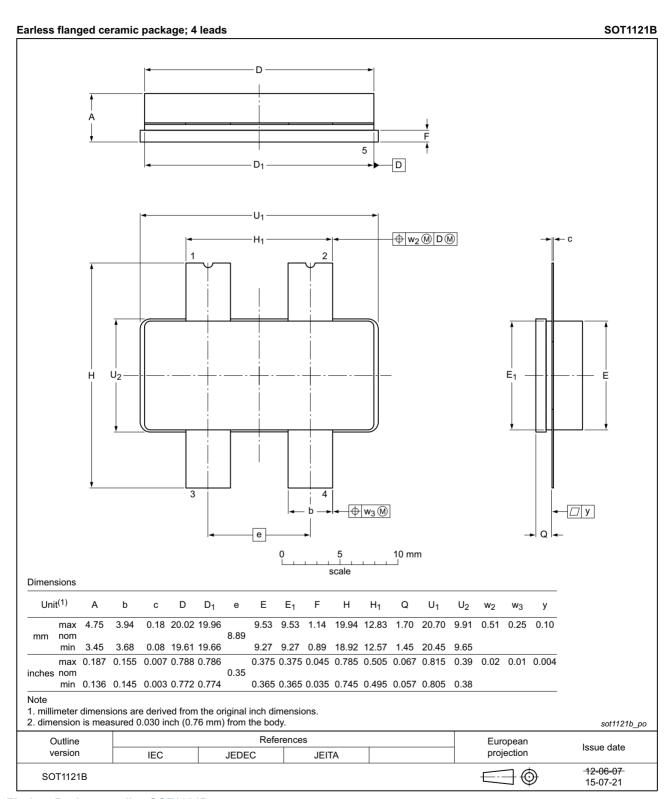


Fig 9. Package outline SOT1121B

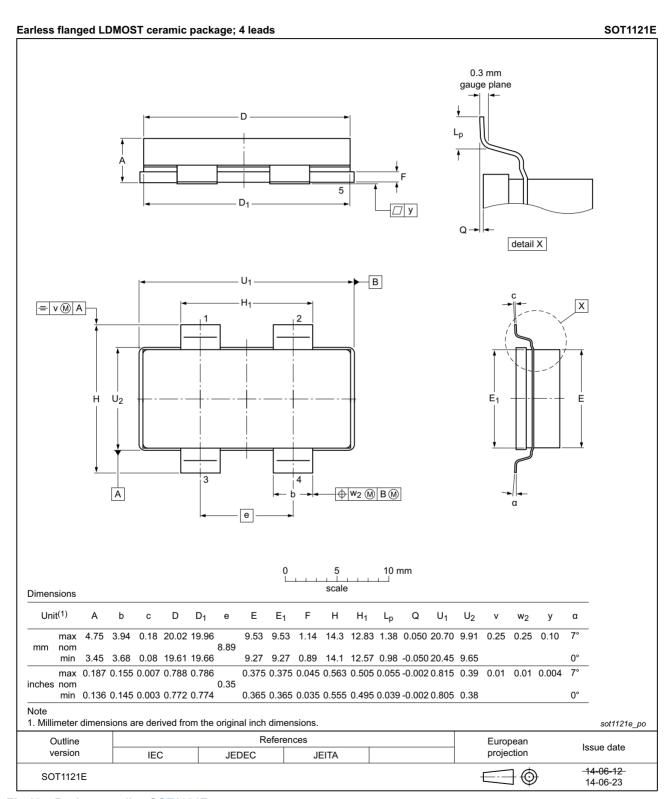


Fig 10. Package outline SOT1121E

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

11. Abbreviations

Table 10. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
MTF	Median Time to Failure
MTTF	Mean Time to Failure
SMD	Surface-Mounted Device
VSWR	Voltage Standing-Wave Ratio

12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLF6G13L-250P_LS-250P_LS-250PG#5	20150901	Product data sheet	-	BLF6G13L-250P_ 6G13LS-250P v.4		
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 					
	 Legal texts have been adapted to the new company name where appropriate. 					
BLF6G13L-250P_LS-250P_LS-250PG v.4	<tbd></tbd>	Product data sheet	-	BLF6G13L-250P_ 6G13LS-250P v.3		
BLF6G13L-250P_6G13LS-250P v.3	20111014	Product data sheet	-	BLF6G13L-250P_ 6G13LS-250P v.2		
BLF6G13L-250P_6G13LS-250P v.2	20110321	Objective data sheet	-	BLF6G13L-250P_ 6G13LS-250P v.1		
BLF6G13L-250P_6G13LS-250P v.1	20101102	Objective data sheet	-	-		

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Power LDMOS transistor

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Power LDMOS transistor

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